## NSN 5961-01-124-5595

Transistor - Page 1 of 2

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-124-5595

**Inclosure Material:** 

Metal

**Overall Length:** 

1.218 inches

**Function For Which Designed:** 

Amplifier

#### **End Application:**

Radar e/i fscm 76301

## **Mounting Facility Quantity:**

1

### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

#### Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

## Thread Size:

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage, dc and 80.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

28.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Test Data Document:**

82577-928884 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Thread Series Designator:

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug and 1 wire hook

## Shelf Life:

N/a

#### Unit Of Measure:

# NSN 5961-01-124-5595

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

